



# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

### Typical Applications

The HMC6147ALC5A is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

### **Features**

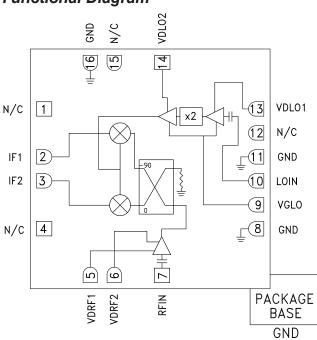
Conversion Gain: 13 dB

Excellent Image Rejection: 25 dB

Output IP3: +12 dBm

16 Lead 5x5 mm SMT Ceramic Package: 25 mm<sup>2</sup>

### **Functional Diagram**



### **General Description**

The HMC6147ALC5A is a compact GaAs MMIC I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 13 dB with 25 dBc of sideband rejection. The HMC6147ALC5A utilizes a low noise amplifier to drive the I/Q mixer where the LO is driven by a X2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC6147ALC5A is a much smaller alternative to hybrid style single sideband converter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications <sup>[1][2]</sup>,  $T_A = +25^{\circ}\text{C}$ , IF = 1000 MHz, LO = +3 dBm, VDLO1,2 = +3V, IDLO1,2 = 150 mA, VDRF1,2 = +3V, IDRF1,2 = 75 mA, USB <sup>[1][2]</sup>

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF		GHz		
Frequency Range, LO		16.5 - 22		GHz
Frequency Range, IF		0 - 4		GHz
Conversion Gain	10	13		dB
Image Rejection	15	25		dBc
1 dB Compression (Output)		1		dBm
IP3 (Input)		2		dBm
Noise Figure		3.5		dB
Supply Current IDLO1 + IDLO2 quiescent [2]		150		mA
Supply Current IDRF1 + IDRF2		75		mA

<sup>[1]</sup> Unless otherwise noted all measurements performed with low side LO, IF = 1000 MHz and external IF 90° hybrid.

<sup>[2]</sup> Adjust Vgg between -2 to 0V to achieve IDLO1 + IDLO2 = 150 mA Typical with RF turned off.

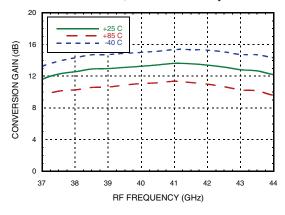




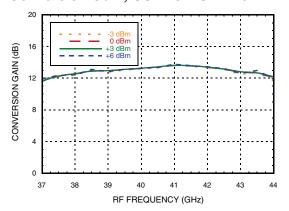
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

# Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

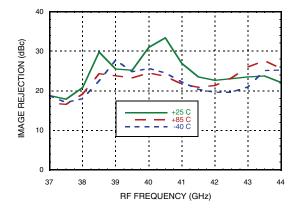
### Conversion Gain, USB vs. Temperature



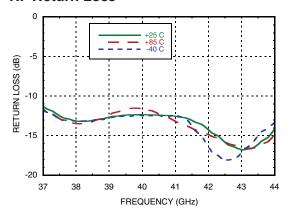
### Conversion Gain, USB vs. LO Drive



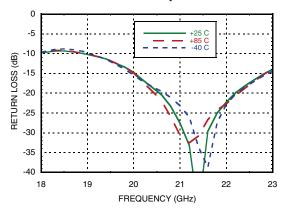
### Image Rejection vs. Temperature



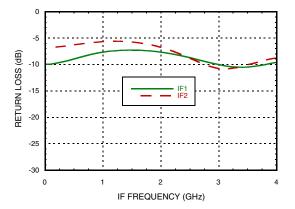
#### **RF Return Loss**



### LO Return Loss vs. Temperature



IF Return Loss [1]



#### [1] Data taken without external IF 90° hybrid

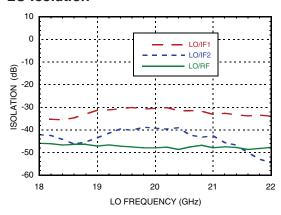




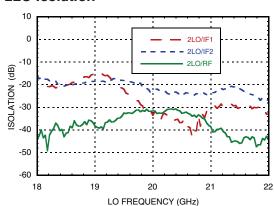
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

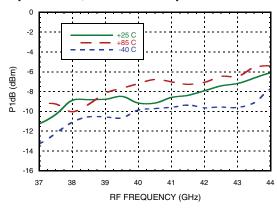
#### LO Isolation



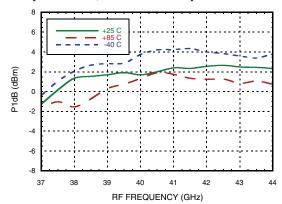
#### 2LO Isolation



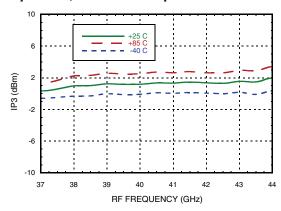
### Input P1dB, USB vs. Temperature



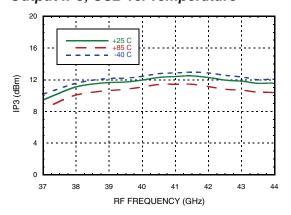
### Output P1dB, USB vs. Temperature



#### Input IP3, USB vs. Temperature



### Output IP3, USB vs. Temperature



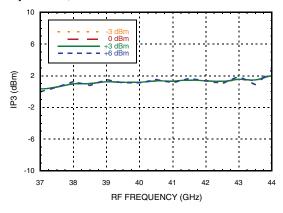




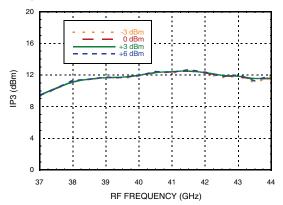
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

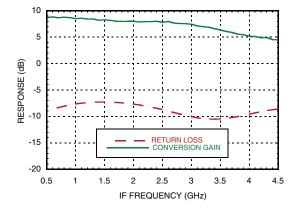
### Input IP3, USB vs. LO Power



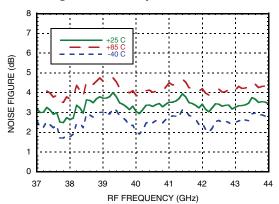
## Output IP3, USB vs. LO Power



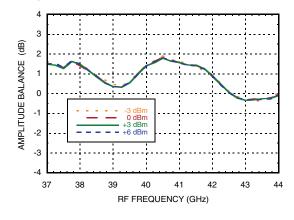
### IF Bandwidth [1]



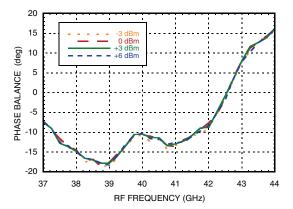
### Noise Figure vs. Temperature



#### Amplitude Balance vs. LO Drive



#### Phase Balance vs. LO Drive



[1] LO = 18GHz

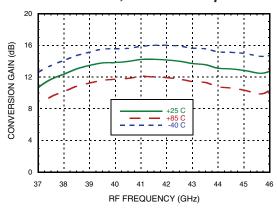




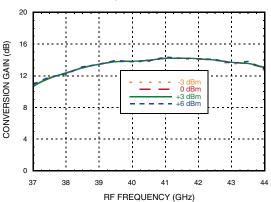
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

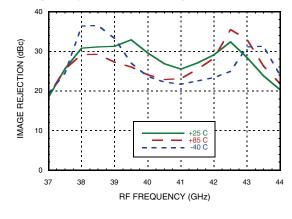
### Conversion Gain, USB vs. Temperature



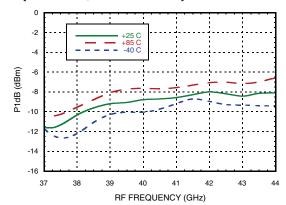
### Conversion Gain, USB vs. LO Drive



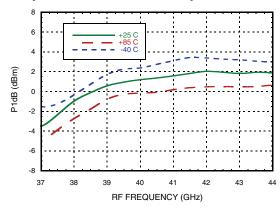
## Image Rejection vs. Temperature



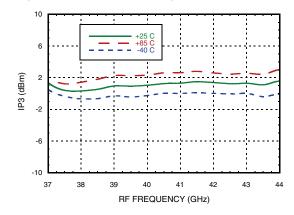
Input P1dB, USB vs. Temperature



### Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



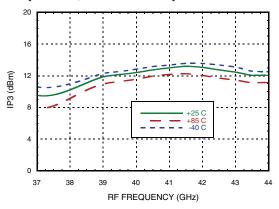




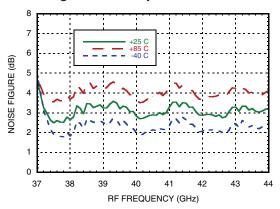
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

### Output IP3, USB vs. Temperature



### Noise Figure vs. Temperature



### MxN Spurious Outputs [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	38	21		
1	17	48	0		
2	xx	xx	47		
3					
4					
5					

RF = 40 GHz @ -8 dBm LO = 19.5 GHz @ +4 dBm

# MxN Spurious Outputs [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	42	16		
1	17	47	0		
2	xx	xx	43		
3					
4					
5				·	

RF = 40 GHz @ -8 dBm LO = 19.0 GHz @ +4 dBm

### **MxN Spurious Outputs** [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	44	20		
1	17	41	0		
2	xx	xx	50		
3					
4					
5					

RF = 40 GHz @ -8 dBm LO = 18.5 GHz @ +4 dBm

[2] All values in dBc below RF power level (2LO + IF) USB

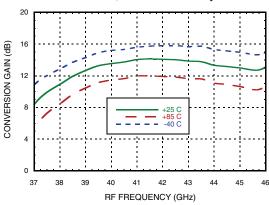
<sup>[1]</sup> Data taken without external IF 90° hybrid

# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

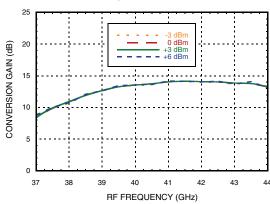


## Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

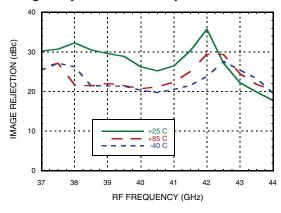
### Conversion Gain, USB vs. Temperature



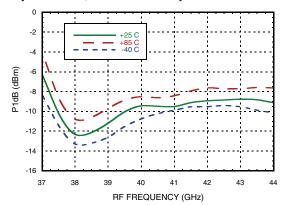
### Conversion Gain, USB vs. LO Drive



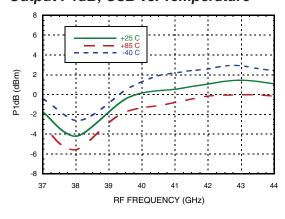
### Image Rejection vs. Temperature



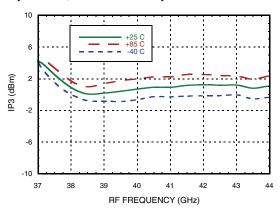
### Input P1dB, USB vs. Temperature



#### Output P1dB, USB vs. Temperature



### Input IP3, USB vs. Temperature



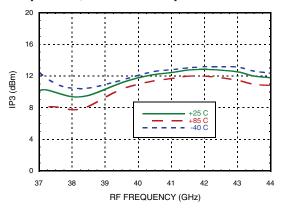




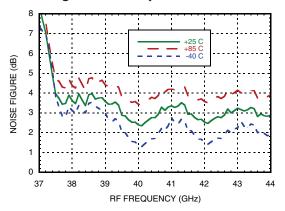
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

### Output IP3, USB vs. Temperature



### Noise Figure vs. Temperature







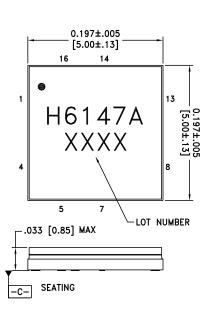
# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

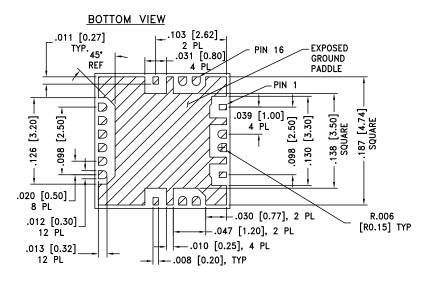
## **Absolute Maximum Ratings**

RF Input	+8 dBm
LO Input	+10 dBm
Bias Voltage, VDLO and VDRF	+3.5V
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 17.8 mW/°C above 85°C)	1.6 W
Thermal Resistance (channel to ground paddle)	56 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class1A



### **Outline Drawing**





#### NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- LEAD AND GROUND PADDLE PLATING: 30 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

## Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC6147ALC5A	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	6147A XXXX

<sup>[1]</sup> Max peak reflow temperature of 260 °C

<sup>[2] 4-</sup>Digit lot number XXXX





# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## **Pin Descriptions**

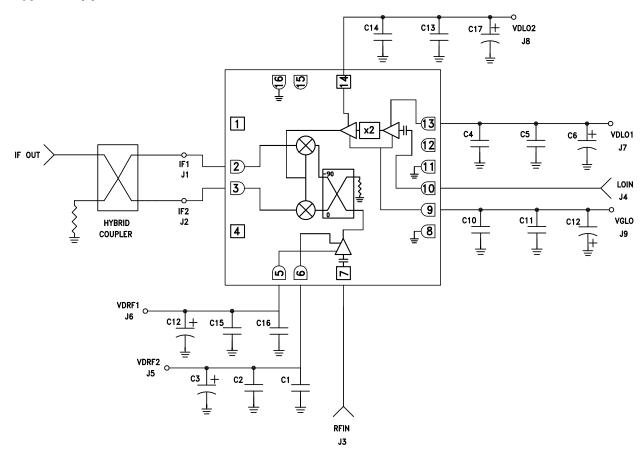
Pin Number	Function	Description	Interface Schematic
1, 4, 12,15	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	IF1	These pins are DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to	IF1,IF2
3	IF2	pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	¥ <del></del>
5	VDRF1		OVDRF1, VDRF2
6	VDRF2	Bias for LNA. The recommended DC voltage is 3V	
7	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN ○── ├──
8,11, 16	GND	These pins and expossed ground paddle must be connected to RF/DC ground.	GND =
9	VG	Adjust VGLO for -1V to 0V to set the multiplier quiescent current to 150mA	VG =
10	LOIN	LO Input Port. The recommended LO Power is 0 to 6 dBM	LOIN O
13	VDLO1	Bias for Multiplier input Buffer Amp. The recommended DC voltage is 3V	OVDLO1, VDLO2
14	VDLO2	Bias for Multiplier output Buffer Amp. The recommended DC voltage is 3V	





# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

## **Typical Application**



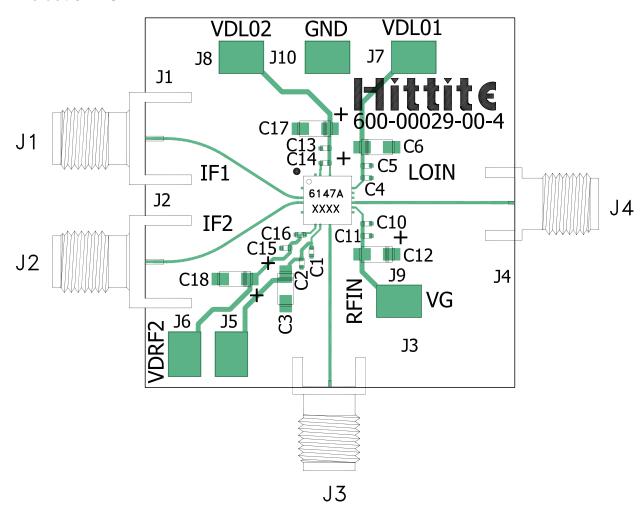
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.	
C2, C5, C11, C13, C15	0.1uF Capacitor, 0402 Pkg.	
C3, C6, C12, C17, C19	4.7 μF Capacitor, Case A Pkg.	





# GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

### **Evaluation PCB**



#### List of Materials for Evaluation PCB Eval01-HMC6147ALC5A [1]

Item	Description
J1, J2	SMA Connector
J3, J4	K-Connector SRI
J5 - J10	DC Pins
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C18	4.7 μF Capacitor, Case A
U1	HMC6147ALC5A Downconverter
PCB [2]	600-00029-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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MAAM-009633-001SMB MASW-000936-001SMB 107712-HMC369LP3 107780-HMC322ALP4 SP000416870 EV1HMC470ALP3
EV1HMC520ALC4 EV1HMC244AG16 MAX2614EVKIT# 124694-HMC742ALP5 SC20ASATEA-8GB-STD MAX2837EVKIT+
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EV1HMC427ALP3E 119197-HMC658LP2 EV1HMC647ALP6 ADL5725-EVALZ 106815-HMC441LM1 EV1HMC1018ALP4
UXN14M9PE MAX2016EVKIT EV1HMC939ALP4 MAX2410EVKIT MAX2204EVKIT+ EV1HMC8073LP3D SIMSA868-DKL
SIMSA868C-DKL SKY65806-636EK1 SKY68020-11EK1 SKY67159-396EK1 SKY66181-11-EK1 SKY65804-696EK1